

An IATF 16949, ISO9001 and ISO 14001/ISO 45001 Certified Company





Silicon Schottky Barrier Diodes

LL101A LL101B LL101C

LL101C

SOD - 80C Mini MELF (LL- 34) RoHS compliant



LL-34 (Mini MELF)

GENERAL DISCRIPTIONS:

The LL101 Series is a metal on silicon Schottky barrier device which is protected by a PN junction guard ring. The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications.

FEATURE:

- 1. This diode is also available in DO-35 case with type designation SD101A, B, C
- 2. This product is available in AEC-Q101 Compliant and PPAP Capable also.

Note: For AEC-Q101 compliant products, please use suffix -AQ in the part number while ordering.

APPLICATION: or general purpose application

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C Unless otherwise specified)

PARAMETER		SYMBOL	VALUE	UNIT
	LL101A		60	
Peak Reverse Voltage	LL101B	V_{RRM}	50	V
	LL101C		40	
Maximum Single Cycle Surge 10µs Square Wave		I _{FSM}	2	Α
Power Dissipation (Infinite Heatsink)		P _{tot}	400 ¹	mW
Junction Temperature		T_j	200	°C
Storage Temperature Range		T_{stg}	-55 to +200	°C

Note:

1. Valid provided that electrodes are kept at ambient temperature.

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ELECTRICAL CHARACTERISTICS at (Ta = 25 °C Unless otherwise specified)

PARAMETER		SYMBOL TEST CONDITIONS		MIN	TYP	MAX	UNIT
Davis a Davidson	LL101A			60			٧
Reverse Breakdown Voltage	LL101B	$V_{(BR)R}$	at I _R = 10µA	50			
	LL101C	(=1.7,1.1		40	-		
	LL101A			-	ŀ	0.41	
	LL101B	V _F	at I _F = 1mA			0.4	V
Forward Voltage	LL101C				ł	0.39	
rorward voltage	LL101A				1	1	
	LL101B		at I _F = 15mA		ł	0.95	V
	LL101C				-	0.9	
Reverse Current	LL101A		at V _R = 50V		-	200	
	LL101B	I _R	at V _R = 40V	-	-	200	рF
	LL101C		at V _R = 30V			200	
Junction Capacitance	LL101A	C_tot			-	2.0	
	LL101B		at $V_R = 0V$, $f = 1MHz$	-	-	2.1	pF
	LL101C				-	2.2	
Reverse Recovery Tim		t _{rr}	at $I_F = I_R = 5 \text{mA}$, recover to $0.1 I_R$			1	ns





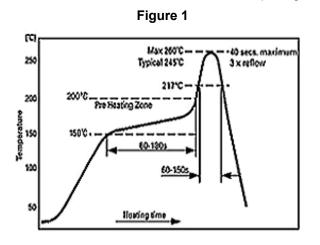
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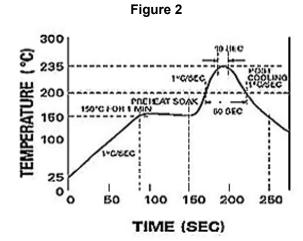
Recommended Reflow Solder Profiles

The recommended reflow solder profiles for Pb and Pb-free devices are shown below.

Figure 1 shows the recommended solder profile for devices that have Pb-free terminal plating, and where a Pb-free solder is used.

Figure 2 shows the recommended solder profile for devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with a leaded solder.





Reflow profiles in tabular form

Profile Feature	Sn-Pb System	Pb-Free System	
Average Ramp-Up Rate	~3°C/second	~3°C/second	
Preheat - Temperature Range - Time	150-170°C 60-180 seconds	150-200°C 60-180 seconds	
Time maintained above: – Temperature – Time	200°C 30-50 seconds	217°C 60-150 seconds	
Peak Temperature	235°C	260°C max.	
Time within +0 -5°C of actual Peak	10 seconds	40 seconds	
Ramp-Down Rate	3°C/second max.	x. 6°C/second max.	

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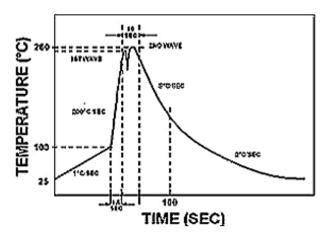




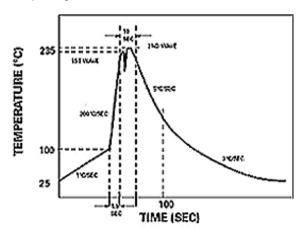
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Recommended Wave Solder Profiles

The Recommended solder Profile For Devices with Pb-free terminal plating where a Pb-free solder is used



The Recommended solder Profile For Devices with Pb-free terminal plating used with leaded solder, or for devices with leaded terminal plating used with leaded solder



Wave Profiles in Tabular Form

Profile Feature	Sn-Pb System	Pb-Free System	
Average Ramp-Up Rate	~200°C/second	~200°C/second	
Heating rate during preheat	Typical 1-2, Max 4°C/sec	Typical 1-2, Max 4°C/Sec	
Final preheat Temperature	Within 125°C of Solder Temp	Within 125°C of Solder Temp	
Peak Temperature	235°C	260°C max.	
Time within +0 -5°C of actual Peak	10 seconds	10 seconds	
Ramp-Down Rate	5°C/second max.	5°C/second max	







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TYPICAL CHARACTERISTICS CURVES

Fig 1: Forward Characteristic Curve

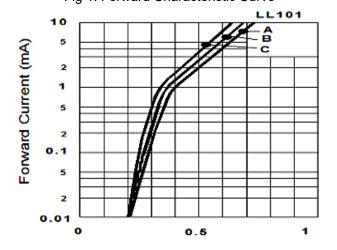


Fig 2: Reverse Characteristic Curve

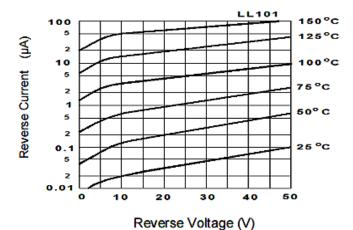


Fig 3: Forward Characteristic Curve

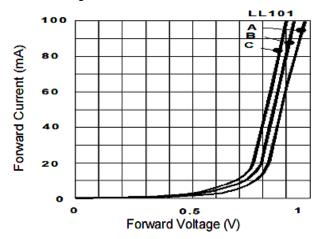
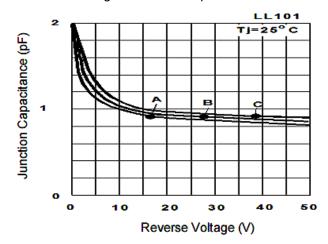


Fig 4: Junction Capacitance



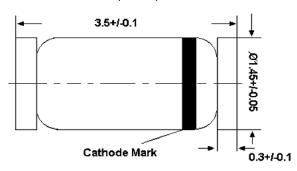




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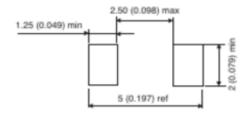
PACKAGE DETAILS

SOD 80C (LL-34) Mini MEL



All Dimensions are mm

Recommended Pad layout



All Dimensions are mm

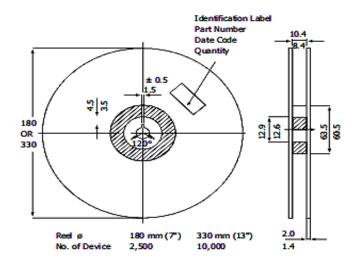


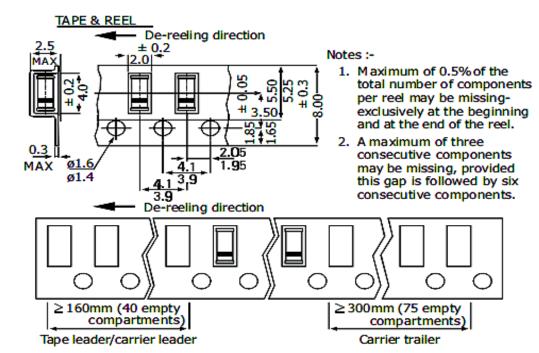






SOD 80C (LL-34) Mini MELF Hermetically Sealed Glass Package





Packing Detail

PACKAGE	STANDARDPACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	GrWt
SOD-80C T&R	2.5K/reel	100 gm/3K pcs	3"×7.5"×7.5"	10.0K	17" x 15" x 13.5"	160.0K	10 kgs
	10K/reel	400 gm/10K pcs	13"×13"×0.5"	10.0K	17" x 15" x 13.5"	300.0K	15 kgs

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Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level					
Level	Time	Condition			
1	Unlimited	≤30 °C / 85% RH			
2	1 Year	≤30 °C / 60% RH			
2a	4 Weeks	≤30 °C / 60% RH			
3	168 Hours	≤30 °C / 60% RH			
4	72 Hours	≤30 °C / 60% RH			
5	48 Hours	≤30 °C / 60% RH			
5a	24 Hours	≤30 °C / 60% RH			
6	Time on Label(TOL)	≤30 °C / 60% RH			









Customer Notes

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered trademark of

Continental Device India Pvt. Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone +91-11-2579 6150, 4141 1112 Fax +91-11-2579 5290, 4141 1119
email@cdil.com www.cdil.com

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